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# ne<mark>x</mark>peria

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Kind regards,

Team Nexperia

14-stage binary ripple counter

Rev. 1 — 23 May 2013

**Product data sheet** 

### 1. General description

The 74HC4020-Q100; 74HCT4020-Q100 are 14-stage binary ripple counters with a clock input ( $\overline{CP}$ ), an overriding asynchronous master reset input (MR) and 12 buffered parallel outputs (Q0, and Q3 to Q13). The counter advances on the HIGH-to-LOW transition of  $\overline{CP}$ . A HIGH on MR clears all counter stages and forces all outputs LOW, independent of the state of  $\overline{CP}$ . Each counter stage is a static toggle flip-flop.. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Input levels:
  - For 74HC4020-Q100: CMOS level
  - For 74HCT4020-Q100: TTL level
- Complies with JEDEC standard no. 7A
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

### 3. Applications

- Frequency dividing circuits
- Time delay circuits
- Control counters

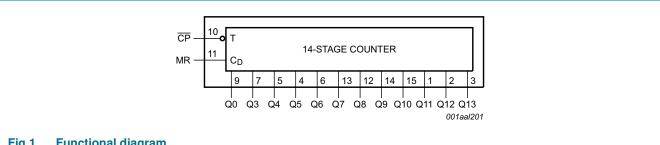


14-stage binary ripple counter

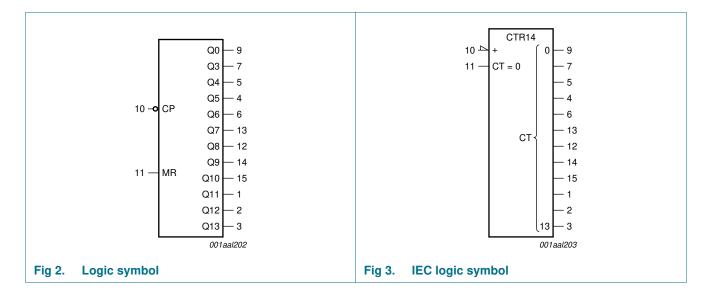
#### **Ordering information** 4.

Table 1. Ordering in	nformation				
Type number	Package				
	Temperature range	Name	Description	Version	
74HC4020D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1	
74HCT4020D-Q100			body width 3.9 mm		
74HC4020PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16	SOT403-1	
74HCT4020PW-Q100			leads; body width 4.4 mm		
74HC4020BQ-Q100	–40 °C to +125 °C	DHVQFN16		SOT763-1	
74HCT4020BQ-Q100			enhanced very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	eads;	

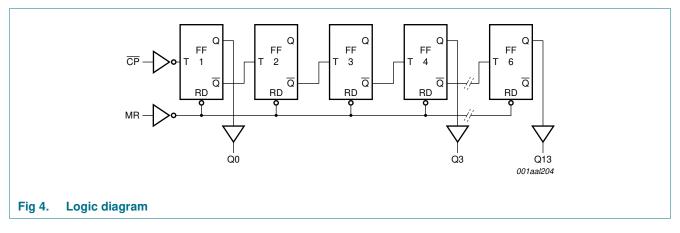
#### **Functional diagram** 5.



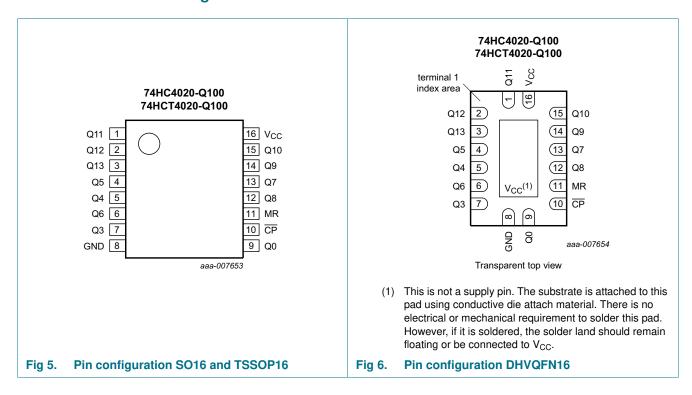




14-stage binary ripple counter



### 6. Pinning information



#### 6.1 Pinning

14-stage binary ripple counter

#### 6.2 Pin description

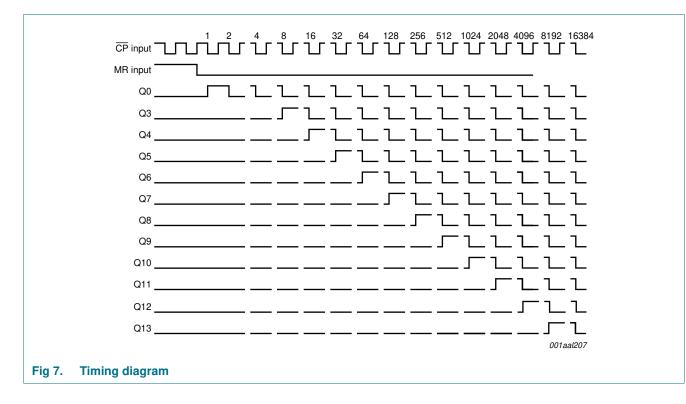
Table 2. Pin des	cription	
Symbol	Pin	Description
Q0, Q3 to Q13	9, 7, 5, 4, 6, 13, 12, 14, 15, 1, 2, 3	output
GND	8	ground (0 V)
CP	10	clock input (HIGH-to-LOW, edge-triggered)
MR	11	master reset input (active HIGH)
V <sub>CC</sub>	16	positive supply voltage

### 7. Functional description

Table 3.	Function table		
Input		Output	
СР		MR	Q0, Q3 to Q13
↑		L	no change
$\downarrow$		L	count
Х		Н	L

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care;  $\uparrow = LOW$ -to-HIGH clock transition;  $\downarrow = HIGH$ -to-LOW clock transition.

#### 7.1 Timing diagram



14-stage binary ripple counter

### 8. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V	-	±20	mA
l <sub>ок</sub>	output clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V	-	±20	mA
lo	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I <sub>CC</sub>	supply current		-	±50	mA
I <sub>GND</sub>	ground current		-	±50	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +125 \ ^{\circ}C$	[1] -	500	mW

For SO16 package: P<sub>tot</sub> derates linearly with 8 mW/K above 70 °C.
 For TSSOP16 package: P<sub>tot</sub> derates linearly with 5.5 mW/K above 60 °C.
 For DHVQFN16 package: P<sub>tot</sub> derates linearly with 4.5 mW/K above 60 °C.

### 9. Recommended operating conditions

#### Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74H	C4020-0	Q100	74H0	Unit		
			Min	Тур	Max	Min	Тур	Max	_
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	$V_{CC}$	0	-	$V_{CC}$	V
Vo	output voltage		0	-	$V_{CC}$	0	-	$V_{CC}$	V
$\Delta t / \Delta V$	input transition rise and fall rate	except for Schmitt trigger inputs							
		$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C

14-stage binary ripple counter

### **10. Static characteristics**

#### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 ℃	Uni
			Min	Тур	Max	Min	Max	Min	Max	
74HC40	20-Q100						1			
VIH	HIGH-level	$V_{CC} = 2.0 V$	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	4.2	-	4.2	-	V
VIL	LOW-level	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = 20 \ \mu A; V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O}$ = 4.0 mA; $V_{CC}$ = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
lı	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1	-	±1	μA
I <sub>CC</sub>	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 6.0 \ V \end{array}$	-	-	8.0	-	80	-	160	μA
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT4	020-Q100									
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$								
	output voltage	I <sub>O</sub> = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
lı	input leakage current	$V_{I} = V_{CC} \text{ or GND};$ $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1	-	±1	μA

14-stage binary ripple counter

Table 6. Static characteristics continu	Jed
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At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C te	–40 °C to +85 °C		–40 °C to +125 °C	
			Min	Тур	Max	Min	Max	Min	Max	
I <sub>CC</sub>	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ \text{A}; \\ V_{CC} = 5.5 \ \text{V} \end{array}$	-	-	8.0	-	80	-	160	μA
△I <sub>CC</sub> additional supply current		$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} - 2.1 \ \text{V}; \ I_{O} = 0 \ \text{A}; \\ \text{other inputs at } V_{CC} \ \text{or GND}; \\ V_{CC} = 4.5 \ \text{V} \ \text{to} \ 5.5 \ \text{V} \end{array}$								
		pin MR	-	110	396	-	495	-	539	μA
		pin CP	-	85	306	-	383	-	417	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

### **11. Dynamic characteristics**

#### Table 7. Dynamic characteristics

GND (ground = 0 V);  $C_L$  = 50 pF unless otherwise specified; for test circuit, see <u>Figure 10</u>

Symbol	Parameter	Conditions		25 °C	;	–40 °C t	o +85 °C	–40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC402	20-Q100				•					
t <sub>pd</sub>	propagation	CP to Q0; see Figure 8 [1]								
	delay	$V_{CC} = 2.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$	-	39	140	-	175	-	210	ns
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$	-	14	28	-	35	-	42	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	11	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$	-	11	24	-	30	-	36	ns
		Qn to Qn+1; see Figure 9								
		$V_{CC} = 2.0 \text{ V}; C_L = 50 \text{ pF}$	-	22	75	-	95	-	110	ns
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$	-	8	15	-	19	-	22	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	6	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$	-	6	13	-	16	-	19	ns
t <sub>PHL</sub>	HIGH to LOW	MR to Qn; see Figure 8								
	propagation delay	$V_{CC}$ =2.0 V; $C_{L}$ = 50 pF	-	55	170	-	215	-	225	ns
	delay	$V_{CC} = 4.5 \text{ V}; C_{L} = 50 \text{ pF}$	-	20	34	-	43	-	51	ns
		$V_{CC} = 5.0 \text{ V}; C_{L} = 15 \text{ pF}$	-	17	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}; C_{L} = 50 \text{ pF}$	-	16	29	-	37	-	43	ns
tt	transition	Qn; see Figure 8 [2]								
	time	$V_{CC} = 2.0 \text{ V}; C_{L} = 50 \text{ pF}$	-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 \text{ V}; C_{L} = 50 \text{ pF}$	-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$	-	6	13	-	16	-	19	ns

14-stage binary ripple counter

Symbol	Parameter	Conditions			25 °C		–40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
tw	pulse width	CP HIGH or LOW; see Figure 8									
		$V_{CC} = 2.0 \text{ V}; C_{L} = 50 \text{ pF}$		80	14	-	100	-	120	-	ns
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		16	4	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V; C <sub>L</sub> = 50 pF		14	3	-	17	-	20	-	ns
		MR HIGH; see Figure 8									
		$V_{CC} = 2.0 \text{ V}; C_{L} = 50 \text{ pF}$		80	17	-	100	-	120	-	ns
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		16	6	-	20	-	24	-	ns
		$V_{CC} = 6.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		14	5	-	17	-	20	-	ns
rec	recovery time	MR to CP; see Figure 8									
	-	$V_{CC} = 2.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		50	6	-	65	-	75	-	ns
		$V_{CC} = 4.5 \text{ V}; C_{L} = 50 \text{ pF}$		10	2	-	13	-	15	-	ns
		$V_{CC} = 6.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		9	2	-	11	-	13	-	ns
f <sub>max</sub>	maximum	see Figure 8									
max	frequency	$V_{CC} = 2.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		6.0	30	-	4.8	_	4.0	-	MH:
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		30	92	-	24	_	20	-	MH
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		_	101	-	-	-	-	-	MH
		$V_{CC} = 6.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		35	109	-	28	-	24	-	MH
	power dissipation capacitance		<u>[3]</u>	-	19	-	-	-	-	-	pF
	propagation	CP to Q0; see Figure 8	[1]								
t <sub>pd</sub>	delay	$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	18	36	-	45	-	54	ns
	-	$V_{CC} = 4.3 \text{ V}, \text{ C}_{L} = 30 \text{ pr}$ $V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		_	15	-		-		-	ns
		$v_{CC} = 5.0 \text{ v}, \text{ CL} = 13 \text{ pr}$ Qn to Qn+1; see Figure 9		-	15	-	-	-	-	-	115
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		_	8	15	_	19	-	22	ne
				-			-				ns
•		$V_{CC} = 5.0 \text{ V}; C_{L} = 15 \text{ pF}$		-	6	-	-	-	-	-	ns
PHL	HIGH to LOW propagation	MR to Qn; see Figure 8			00	45		50		<u></u>	
	delay	$V_{CC} = 4.5 \text{ V}; C_{L} = 50 \text{ pF}$		-	22	45	-	56	-	68	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	[2]	-	19	-	-	-	-	-	ns
t	transition time	Qn; see Figure 8	[2]		-	4 -		10		00	
		$V_{CC} = 4.5 \text{ V}; C_{L} = 50 \text{ pF}$		-	7	15	-	19	-	22	ns
W	pulse width	CP HIGH or LOW; see <u>Figure 8</u>									
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		20	7	-	25	-	30	-	ns
		MR HIGH; see Figure 8									
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$		20	8	-	25	-	30	-	ns
t <sub>rec</sub>	recovery time	MR to CP; see Figure 8									
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$		10	2	-	13	-	15	-	ns

#### Table 7. Dynamic characteristics ...continued

GND (ground = 0 V):  $C_1$  = 50 pF unless otherwise specified; for test circuit, see Figure 10

74HC\_HCT4020\_Q100
Product data sheet

14-stage binary ripple counter

Symbol	Parameter	Conditions	25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
f <sub>max</sub> maximum		see Figure 8								
	frequency	$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$	25	47	-	20	-	17	-	MHz
		$V_{CC} = 5.0 \text{ V}; C_{L} = 15 \text{ pF}$	-	52	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	[3	L -	20	-	-	-	-	-	pF

#### Table 7. Dynamic characteristics ... continued

[1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

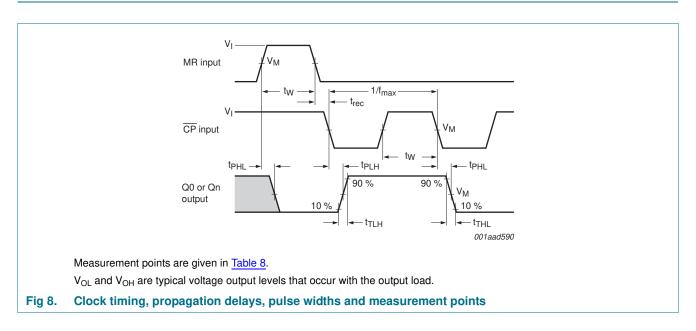
 $f_o = output frequency in MHz;$ 

 $\Sigma (C_L \times V_{CC}^2 \times f_o) = sum of outputs;$ 

C<sub>L</sub> = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V.

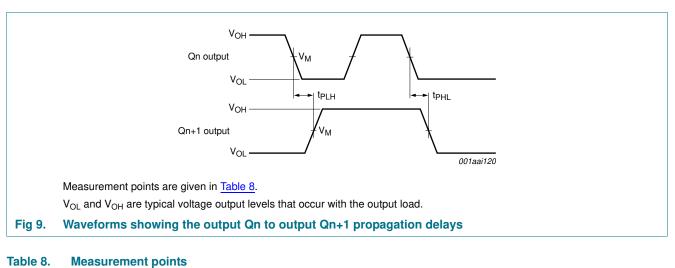
### 12. Waveforms



#### **NXP Semiconductors**

## 74HC4020-Q100; 74HCT4020-Q100

14-stage binary ripple counter



Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74HC4020-Q100	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
74HCT4020-Q100	1.3 V	1.3 V

14-stage binary ripple counter

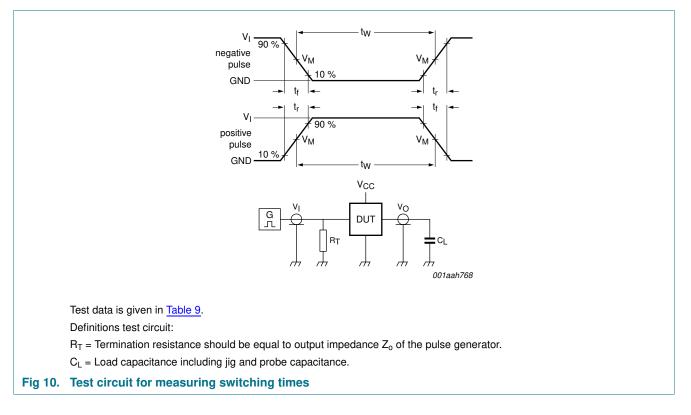
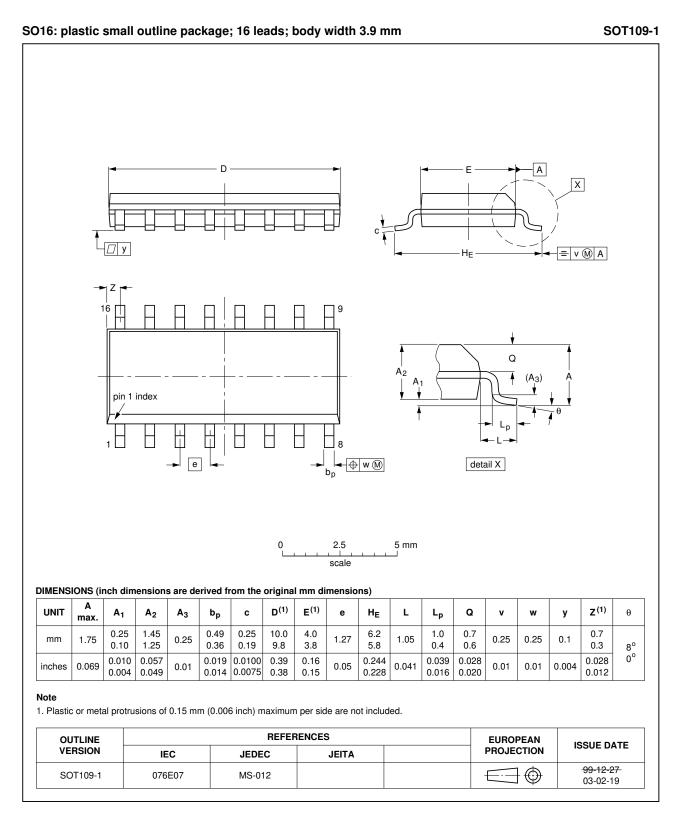


Table 9. Test data					
Туре	Input		Load		
	VI	t <sub>r</sub> , t <sub>f</sub>	CL		
74HC4020-Q100	V <sub>CC</sub>	6 ns	15 pF, 50 pF		
74HCT4020-Q100	3 V	6 ns	15 pF, 50 pF		

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### 13. Package outline

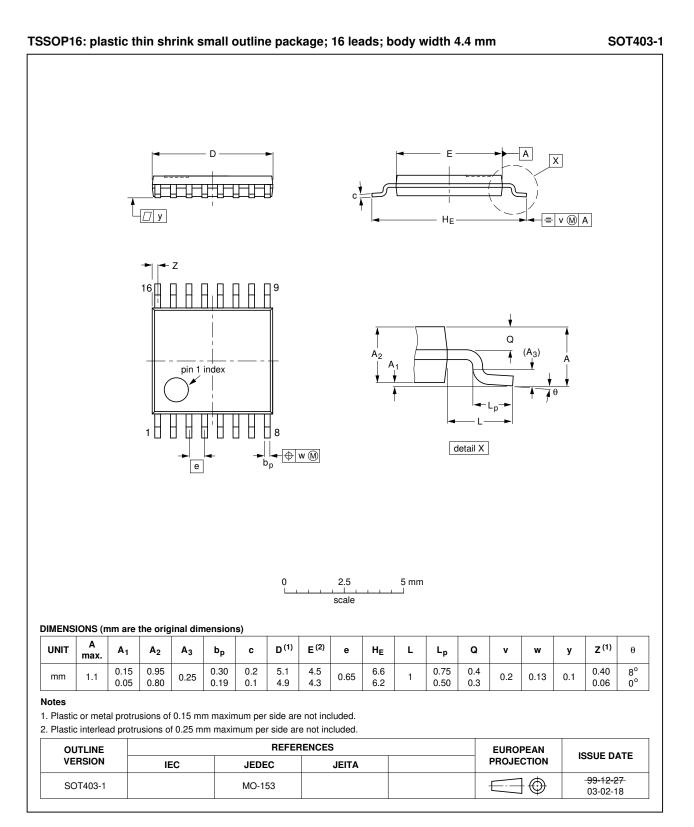


#### Fig 11. Package outline SOT109-1 (SO16)

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74HC HCT4020 Q100

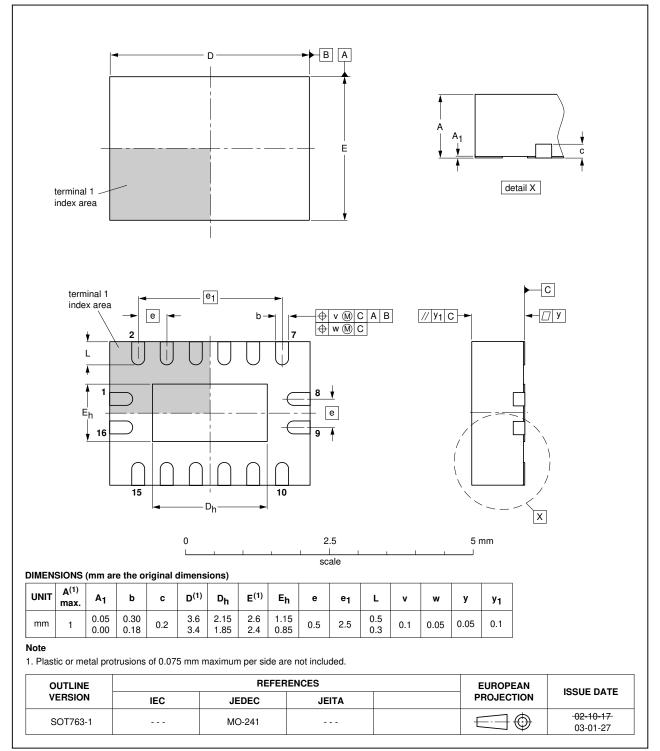
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#### Fig 12. Package outline SOT403-1 (TSSOP16)

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#### DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

Fig 13. Package outline SOT763-1 (DHVQFN16)

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### 14. Abbreviations

Table 10.	10. Abbreviations	
Acronym	Description	
CMOS	Complementary Metal-Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	
MIL	Military	
MM	Machine Model	
TTL	Transistor-Transistor Logic	

### 15. Revision history

Table 11. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT4020_Q100 v.1	20130523	Product data sheet	-	-		

### 16. Legal information

#### 16.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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